

# BCP56 Series, SBCP56 Series

## NPN Silicon Epitaxial Transistor

These NPN Silicon Epitaxial transistors are designed for use in audio amplifier applications. The device is housed in the SOT-223 package, which is designed for medium power surface mount applications.

### Features

- High Current: 1.0 A
- The SOT-223 package can be soldered using wave or reflow. The formed leads absorb thermal stress during soldering, eliminating the possibility of damage to the die
- Available in 12 mm Tape and Reel  
Use BCP56T1 to Order the 7 inch/1000 Unit Reel  
Use BCP56T3 to Order the 13 inch/4000 Unit Reel
- PNP Complement is BCP53T1
- AEC-Q101 Qualified and PPAP Capable
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

### MAXIMUM RATINGS ( $T_C = 25^\circ\text{C}$ unless otherwise noted)

| Rating                                                                                            | Symbol         | Value      | Unit                      |
|---------------------------------------------------------------------------------------------------|----------------|------------|---------------------------|
| Collector-Emitter Voltage                                                                         | $V_{CEO}$      | 80         | Vdc                       |
| Collector-Base Voltage                                                                            | $V_{CBO}$      | 100        | Vdc                       |
| Emitter-Base Voltage                                                                              | $V_{EBO}$      | 5          | Vdc                       |
| Collector Current                                                                                 | $I_C$          | 1          | Adc                       |
| Total Power Dissipation<br>@ $T_A = 25^\circ\text{C}$ (Note 1)<br>Derate above $25^\circ\text{C}$ | $P_D$          | 1.5<br>12  | W<br>mW/ $^\circ\text{C}$ |
| Operating and Storage<br>Temperature Range                                                        | $T_J, T_{stg}$ | -65 to 150 | $^\circ\text{C}$          |

### THERMAL CHARACTERISTICS

| Characteristic                                                       | Symbol          | Max       | Unit                      |
|----------------------------------------------------------------------|-----------------|-----------|---------------------------|
| Thermal Resistance,<br>Junction-to-Ambient<br>(surface mounted)      | $R_{\theta JA}$ | 83.3      | $^\circ\text{C}/\text{W}$ |
| Maximum Temperature for<br>Soldering Purposes<br>Time in Solder Bath | $T_L$           | 260<br>10 | $^\circ\text{C}$<br>Sec   |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

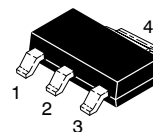
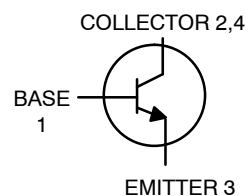
1. Device mounted on a FR-4 glass epoxy printed circuit board 1.575 in x 1.575 in x 0.0625 in; mounting pad for the collector lead = 0.93 sq in.



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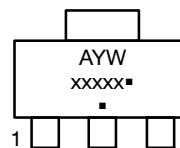
<http://onsemi.com>

## MEDIUM POWER NPN SILICON HIGH CURRENT TRANSISTOR SURFACE MOUNT



SOT-223  
CASE 318E  
STYLE 1

### MARKING DIAGRAM



xx = Specific Device Code  
A = Assembly Location  
Y = Year  
W = Work Week  
▪ = Pb-Free Package  
(Note: Microdot may be in either location)

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

## BCP56 Series, SBCP56 Series

### ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

| Characteristics                                                                        | Symbol               | Min | Typ | Max | Unit |
|----------------------------------------------------------------------------------------|----------------------|-----|-----|-----|------|
| <b>OFF CHARACTERISTICS</b>                                                             |                      |     |     |     |      |
| Collector–Base Breakdown Voltage<br>(I <sub>C</sub> = 100 µAdc, I <sub>E</sub> = 0)    | V <sub>(BR)CBO</sub> | 100 | –   | –   | Vdc  |
| Collector–Emitter Breakdown Voltage<br>(I <sub>C</sub> = 1.0 mAdc, I <sub>B</sub> = 0) | V <sub>(BR)CEO</sub> | 80  | –   | –   | Vdc  |
| Emitter–Base Breakdown Voltage<br>(I <sub>E</sub> = 10 µAdc, I <sub>C</sub> = 0)       | V <sub>(BR)EBO</sub> | 5.0 | –   | –   | Vdc  |
| Collector–Base Cutoff Current<br>(V <sub>CB</sub> = 30 Vdc, I <sub>E</sub> = 0)        | I <sub>CBO</sub>     | –   | –   | 100 | nAdc |
| Emitter–Base Cutoff Current<br>(V <sub>EB</sub> = 5.0 Vdc, I <sub>C</sub> = 0)         | I <sub>EBO</sub>     | –   | –   | 10  | µAdc |

### ON CHARACTERISTICS (Note 2)

|                                                                                                                                                                                                                                                                                                           |                      |                             |                       |                             |     |
|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------------------|-----------------------------|-----------------------|-----------------------------|-----|
| DC Current Gain<br>(I <sub>C</sub> = 5.0 mA, V <sub>CE</sub> = 2.0 V) All Part Types<br>(I <sub>C</sub> = 150 mA, V <sub>CE</sub> = 2.0 V) BCP56T1, SBCP56T1, SBCP56T3<br>BCP56–10T1, SBCP56–10T1<br>BCP56–16T1, SBCP56–16T1, SBCP56–16T3<br>(I <sub>C</sub> = 500 mA, V <sub>CE</sub> = 2.0 V) All Types | h <sub>FE</sub>      | 25<br>40<br>63<br>100<br>25 | –<br>–<br>–<br>–<br>– | –<br>250<br>160<br>250<br>– | –   |
| Collector–Emitter Saturation Voltage<br>(I <sub>C</sub> = 500 mAdc, I <sub>B</sub> = 50 mAdc)                                                                                                                                                                                                             | V <sub>CE(sat)</sub> | –                           | –                     | 0.5                         | Vdc |
| Base–Emitter On Voltage<br>(I <sub>C</sub> = 500 mAdc, V <sub>CE</sub> = 2.0 Vdc)                                                                                                                                                                                                                         | V <sub>BE(on)</sub>  | –                           | –                     | 1.0                         | Vdc |

### DYNAMIC CHARACTERISTICS

|                                                                                                       |                |   |     |   |     |
|-------------------------------------------------------------------------------------------------------|----------------|---|-----|---|-----|
| Current–Gain – Bandwidth Product<br>(I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 5.0 Vdc, f = 35 MHz) | f <sub>T</sub> | – | 130 | – | MHz |
|-------------------------------------------------------------------------------------------------------|----------------|---|-----|---|-----|

2. Pulse Test: Pulse Width ≤ 300 µs, Duty Cycle ≤ 2.0%

### ORDERING INFORMATION

| Device       | Marking | Package              | Shipping <sup>†</sup> |
|--------------|---------|----------------------|-----------------------|
| BCP56T1G     | BH      | SOT–223<br>(Pb–Free) | 1000 / Tape & Reel    |
| SBCP56T1G    |         |                      |                       |
| BCP56T3G     | BH      | SOT–223<br>(Pb–Free) | 4000 / Tape & Reel    |
| SBCP56T3G    |         |                      |                       |
| BCP56–10T1G  | BH–10   | SOT–223<br>(Pb–Free) | 1000 / Tape & Reel    |
| SBCP56–10T1G |         |                      |                       |
| BCP56–16T1G  | BH–16   | SOT–223<br>(Pb–Free) | 1000 / Tape & Reel    |
| SBCP56–16T1G |         |                      |                       |
| BCP56–16T3G  | BH–16   | SOT–223<br>(Pb–Free) | 4000 / Tape & Reel    |
| SBCP56–16T3G |         |                      |                       |

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# BCP56 Series, SBCP56 Series

## TYPICAL ELECTRICAL CHARACTERISTICS

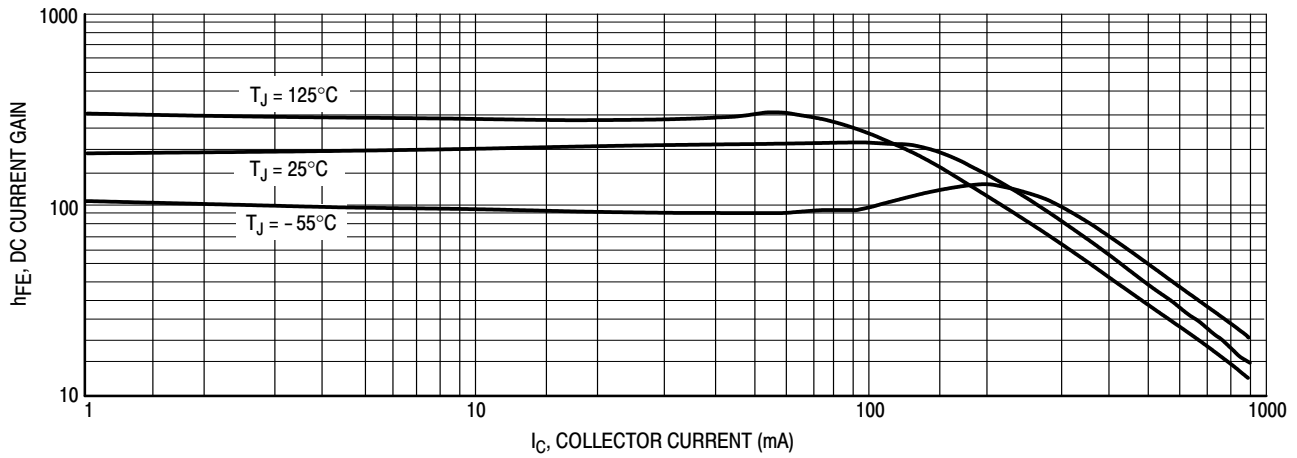


Figure 1. DC Current Gain

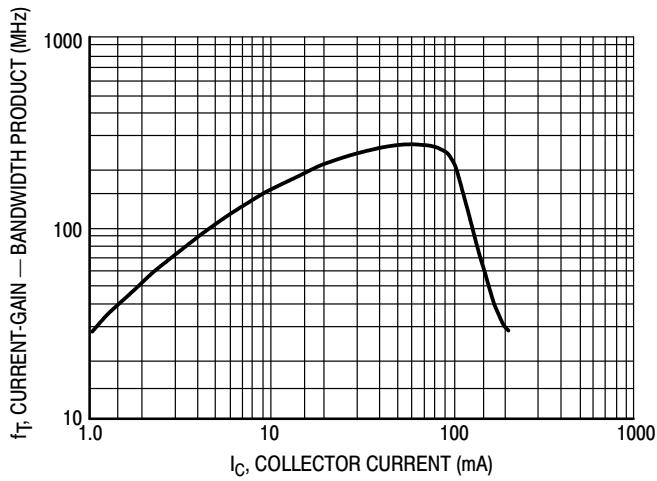


Figure 2. Current-Gain - Bandwidth Product

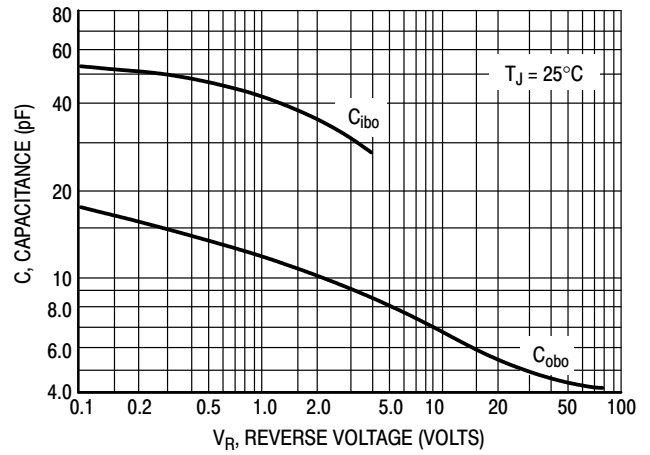


Figure 3. Capacitance

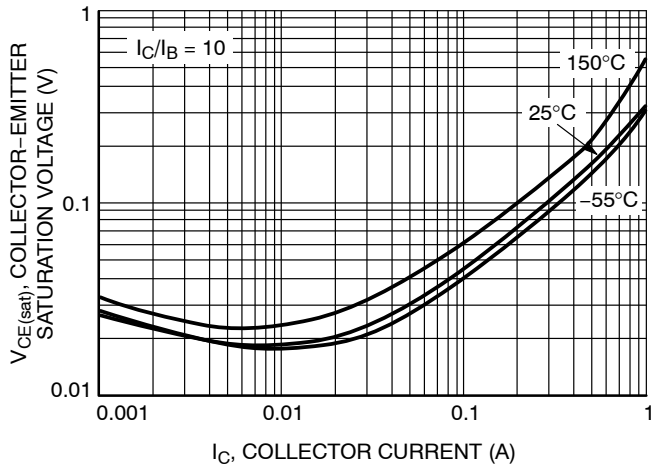


Figure 4. Collector Emitter Saturation Voltage vs. Collector Current

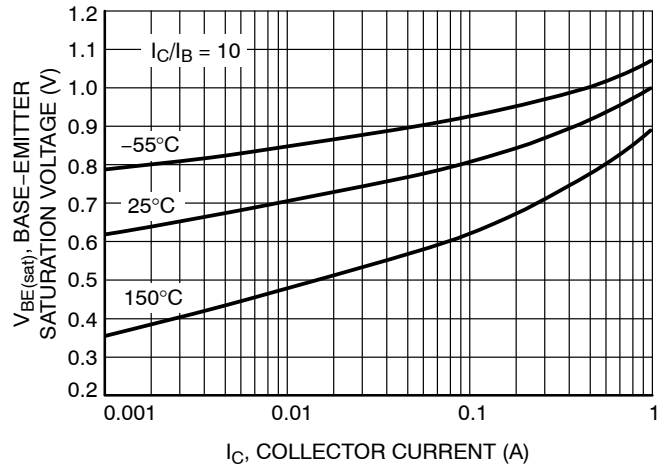


Figure 5. Base Emitter Saturation Voltage vs. Collector Current

# BCP56 Series, SBCP56 Series

## TYPICAL ELECTRICAL CHARACTERISTICS

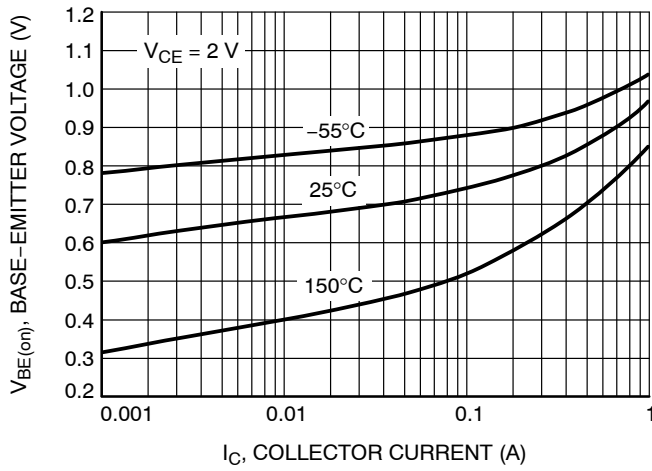


**Figure 6. Base Emitter Voltage vs. Collector Current**

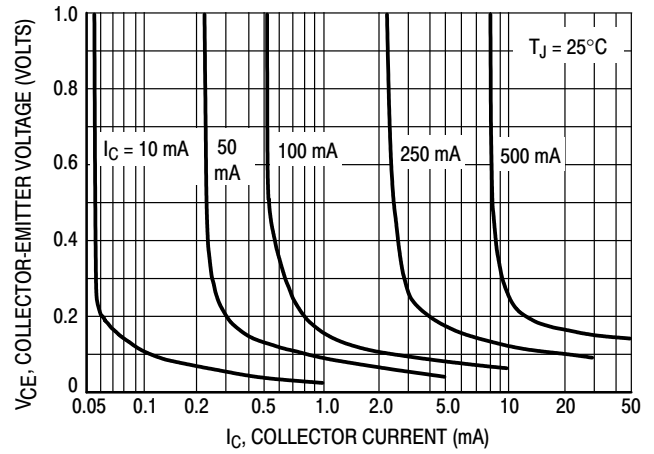


**Figure 7. Collector Saturation Region**

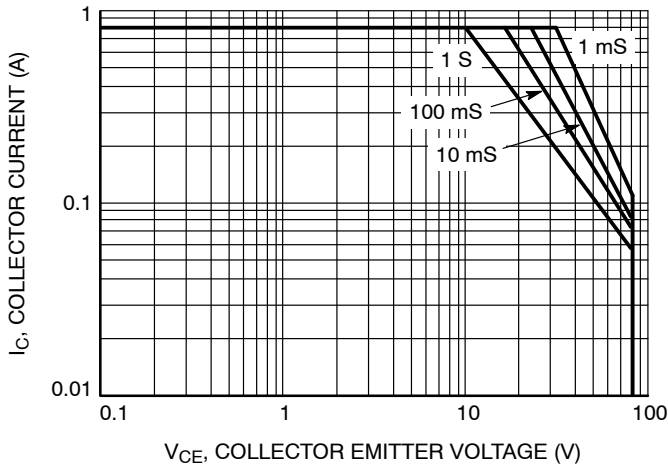


**Figure 8. Safe Operating Area**

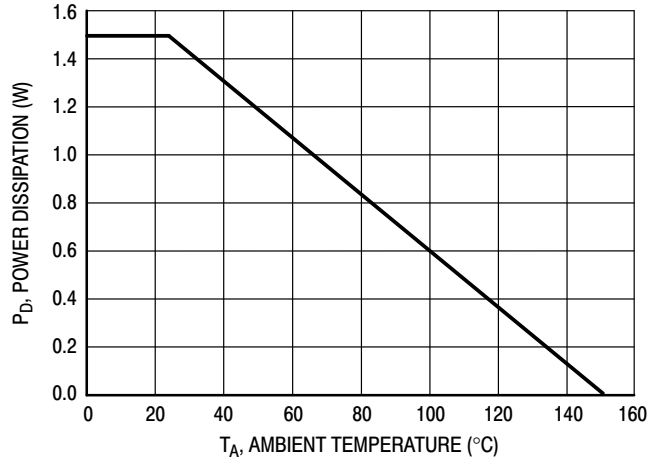
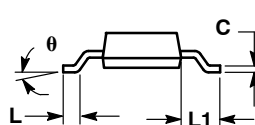
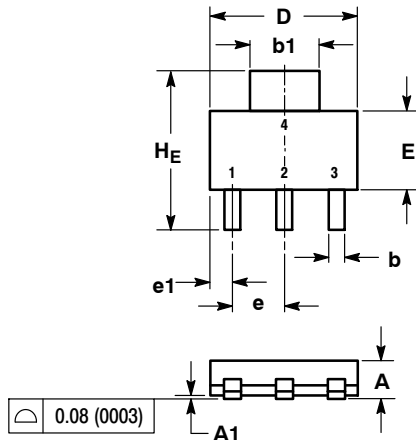


**Figure 9. Power Derating Curve**

# BCP56 Series, SBCP56 Series

## PACKAGE DIMENSIONS

SOT-223 (TO-261)  
CASE 318E-04  
ISSUE N



### NOTES:

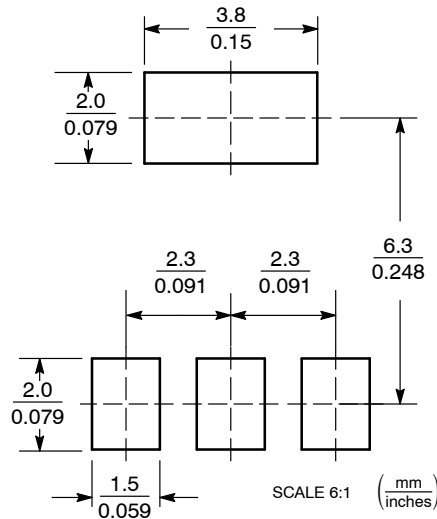
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCH.

| DIM | MILLIMETERS |      |      | INCHES |       |       |
|-----|-------------|------|------|--------|-------|-------|
|     | MIN         | NOM  | MAX  | MIN    | NOM   | MAX   |
| A   | 1.50        | 1.63 | 1.75 | 0.060  | 0.064 | 0.068 |
| A1  | 0.02        | 0.06 | 0.10 | 0.001  | 0.002 | 0.004 |
| b   | 0.60        | 0.75 | 0.89 | 0.024  | 0.030 | 0.035 |
| b1  | 2.90        | 3.06 | 3.20 | 0.115  | 0.121 | 0.126 |
| c   | 0.24        | 0.29 | 0.35 | 0.009  | 0.012 | 0.014 |
| D   | 6.30        | 6.50 | 6.70 | 0.249  | 0.256 | 0.263 |
| E   | 3.30        | 3.50 | 3.70 | 0.130  | 0.138 | 0.145 |
| e   | 2.20        | 2.30 | 2.40 | 0.087  | 0.091 | 0.094 |
| e1  | 0.85        | 0.94 | 1.05 | 0.033  | 0.037 | 0.041 |
| L   | 0.20        | ---  | ---  | 0.008  | ---   | ---   |
| L1  | 1.50        | 1.75 | 2.00 | 0.060  | 0.069 | 0.078 |
| H_E | 6.70        | 7.00 | 7.30 | 0.264  | 0.276 | 0.287 |
| θ   | 0°          | ---  | 10°  | 0°     | ---   | 10°   |

### STYLE 1:

1. BASE
2. COLLECTOR
3. EMITTER
4. COLLECTOR

### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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